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74LVQ86 Low Voltage Quad 2-Input Exclusive-OR Gate

General Description

The LVQ86 contains four 2-input exclusive-OR gates.

Features

■ Ideal for low power/low noise 3.3V applications

February 1992

Revised June 2003

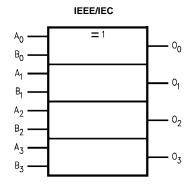
- Guaranteed simultaneous switching noise level and
- dynamic threshold performance
- Guaranteed pin-to-pin skew AC performance
- Guaranteed incident wave switching into 75Ω

Ordering Code:

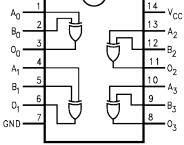
Order Number	Package Number	Package Description
74LVQ86SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVQ86SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
Device also available in	n Tape and Reel. Specify b	by appending suffix letter "X" to the ordering code.

Reel. Specify by appending suffix letter "X

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description
A ₀ -A ₃	Inputs
B ₀ –B ₃	Inputs
O ₀ –O ₃	Outputs

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +7.0V	C
DC Input Diode Current (I _{IK})		S
$V_{I} = -0.5V$	–20 mA	
$V_I = V_{CC} + 0.5V$	+20 mA	lr
DC Input Voltage (VI)	–0.5V to V_{CC} + 0.5V	C
DC Output Diode Current (I _{OK})		C
$V_0 = -0.5V$	–20 mA	
$V_O = V_{CC} + 0.5V$	+20 mA	Ν
DC Output Voltage (V _O)	–0.5V to V_{CC} + 0.5V	
DC Output Source		
or Sink Current (I _O)	±50 mA	Not
DC V_{CC} or Ground Current		the ope
(I _{CC} or I _{GND})	±200 mA	Cha The
Storage Temperature (T _{STG})	-65°C to +150°C	for a
DC Latch-Up Source or		Not
Sink Current	±100 mA	

Recommended Operating Conditions (Note 2)

Supply Voltage (V _{CC})	
LVQ	2.0V to 3.6V
Input Voltage (V _I)	0V to V _{CC}
Output Voltage (V _O)	0V to V_{CC}
Operating Temperature (T _A)	
74LVQ	$-40^\circ C$ to $+85^\circ C$
Minimum Input Edge Rate ($\Delta V/\Delta t$)	
V _{IN} from 0.8V to 2.0V	
V _{CC} @ 3.0V	125 mV/ns
Note 1: The "Absolute Maximum Ratings" are th	

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Vcc	T _A =	25°C	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	Units	Conditions
Symbol	Falameter	(V)	Тур	Gu	uaranteed Limits	Units	Conditions
VIH	Minimum High Level	3.0	1.5	2.0	2.0	V	$V_{OUT} = 0.1V$
	Input Voltage						or $V_{CC} - 0.1V$
V _{IL}	Maximum Low Level	3.0	1.5	0.8	0.8	V	V _{OUT} = 0.1V
	Input Voltage						or $V_{CC} - 0.1V$
V _{OH}	Minimum High Level	3.0	2.99	2.9	2.9	V	I _{OUT} = -50 μA
	Output Voltage	3.0		2.58	2.48	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$
				2.50			$I_{OH} = -12 \text{ mA}$
V _{OL}	Maximum Low Level	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
	Output Voltage	3.0		0.36	0.44		$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$
		5.0		0.50	0.44		$I_{OL} = 12 \text{ mA}$
I _{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}, GND$
I _{OLD}	Minimum Dynamic (Note 4)	3.6			36	mA	V _{OLD} = 0.8V Max (Note 5)
I _{OHD}	Output Current	3.6			-25	mA	V _{OHD} = 2.0V Min (Note 5)
I _{CC}	Maximum Quiescent	3.6		2.0	20.0	μA	$V_{IN} = V_{CC}$ or GND
	Supply Current	0.0		2.0	20.0	μΛ	VIN - VCC OF GIVE
V _{OLP}	Quiet Output	3.3	0.5	0.8		v	(Note 6)(Note 7)
	Maximum Dynamic V _{OL}	5.5	0.5	0.0		v	
V _{OLV}	Quiet Output	3.3	-0.5	-0.8		v	(Note 6)(Note 7)
	Minimum Dynamic V _{OL}	5.5	-0.5	-0.0		v	
V _{IHD}	Maximum High Level	3.3	1.8	2.0		v	(Note 6)(Note 8)
	Dynamic Input Voltage	0.0	1.0	2.0		, ,	(
V _{ILD}	Maximum Low Level	3.3	1.8	0.8		V	(Note 6)(Note 8)
	Dynamic Input Voltage	0.0					(

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 20 ms, one output loaded at a time.

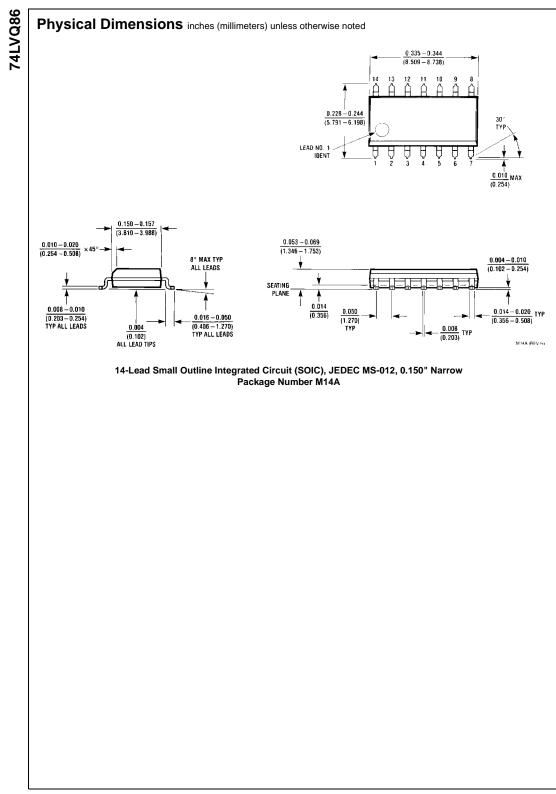
Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ. Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{ILD}), f = 1 MHz.

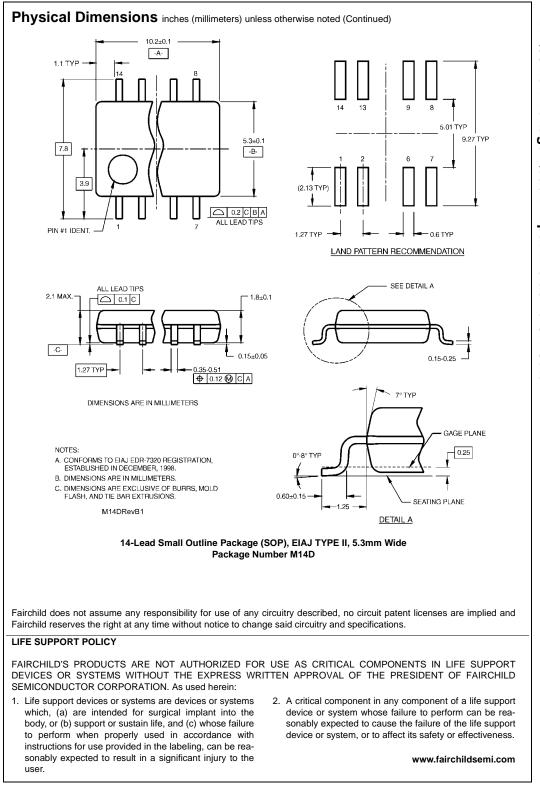
				$T_A = +25^{\circ}C$		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		
Symbol	Parameter	V _{cc}	C _L = 50 pF			$C_L = 50 \text{ pF}$		Units
		(V)	Min	Тур	Мах	Min	Max	1
t _{PLH}	Propagation Delay	2.7	2.0	7.2	16.2	1.5	18.0	ns
		3.3 ± 0.3	2.0	6.0	11.5	1.5	12.5	
t _{PHL}	Propagation Delay	2.7	2.0	7.8	16.2	1.5	18.0	
		3.3 ± 0.3	2.0	6.5	11.5	1.5	12.5	ns
t _{OSHL} ,	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t _{OSLH}	(Note 9)	3.3 ± 0.3		1.0	1.5		1.5	
	is defined as the absolute value of the applies to any outputs switching in the	same direction, eith		W (t _{OSHL}) or L				
Symbol	Parameter		Тур	Unit	ts	C	onditions	
C _{IN} Input Capacitance			4.5	pF		V _{CC} = Open		
	C _{PD} (Note 10) Power Dissipation Capacitance							

Note 10: C_{PD} is measured at 10 MHz.



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